WAB300M12BM3

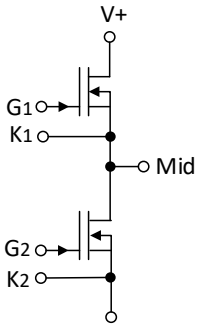
V_{DS}	1200 V
I_{DS}	300 A

1200 V, 300 A All-Silicon Carbide
THB-80 Qualified, Switching Optimized, Half-Bridge Module

Technical Features

- Industry Standard 62 mm Footprint
- High Humidity Operation THB-80 (HV-H3TRB)
- High Junction Temperature (175 °C) Operation
- Implements Switching Optimized Third Generation SiC MOSFET Technology
- Low Inductance (10.2 nH) Design
- Silicon Nitride Insulator and Copper Baseplate





Applications

- Railway & Traction
- Solar
- EV Chargers
- Industrial Automation & Testing

System Benefits

- Fast Time-to-Market with Minimal Development Required for Transition from 62 mm Si IGBT Packages
- Increased System Efficiency, due to Low Switching & Conduction Losses of SiC
- High Reliability Material Selection

Key Parameters

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions	Note
Drain-Source Voltage	V_{DS}			1200	V	T_C = 25 °C	
Gate-Source Voltage, Maximum Value	$V_{GS(max)}$	-8		+19		Transient	Note 1 Fig. 32
Gate-Source Voltage, Recommended	$V_{GS(op)}$		-4/+15			Static	
DC Continuous Drain Current	I_D		382		A	V_{GS} = 15 V, T_C = 25 °C, T_{VJ} ≤ 175 °C	Notes 2, 3 Fig. 20
			270			V_{GS} = 15 V, T_C = 90 °C, T_{VJ} ≤ 175 °C	
DC Source-Drain Current (Body Diode)	$I_{SD(BD)}$		190			V_{GS} = -4 V, T_C = 25 °C, T_{VJ} ≤ 175 °C	
Pulsed Drain-Source Current	I_{DM}		600			t_{Pmax} limited by T_{VJmax} V_{GS} = 15 V, T_C = 25 °C	
Power Dissipation	P_D		938		W	T_C = 25 °C, T_{VJ} ≤ 175 °C	Note 4 Fig. 20
Virtual Junction Temperature	$T_{VJ(op)}$	-40		175	°C		

Note (1): Recommended turn-on gate voltage is 15 V with ±5 % regulation tolerance
Note (2): Current limit at T_C = 90 °C calculated by $I_{D(max)} = \sqrt{(P_D/R_{DS(typ)}(T_{VJ(max)}, I_{D(max)}))}$
Note (3): Verified by design
Note (4): $P_D = (T_{VJ} - T_C)/R_{TH(JC,typ)}$

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MOSFET Characteristics (Per Position) (T_{VJ} = 25 °C Unless Otherwise Specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions	Note
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	1200			V	V_{GS} = 0 V, T_{VJ} = -40 °C	
Gate Threshold Voltage	$V_{GS(th)}$	1.8	2.5	3.6	V	V_{DS} = V_{GS}, I_D = 92 mA	
			2.0			V_{DS} = V_{GS}, I_D = 92 mA, T_{VJ} = 175 °C	
Zero Gate Voltage Drain Current	I_{DSS}		10	150	µA	V_{GS} = 0 V, V_{DS} = 1200 V	
Gate-Source Leakage Current	I_{GSS}		0.05	1		V_{GS} = 15 V, V_{DS} = 0 V	
Drain-Source On-State Resistance (Devices Only)	$R_{DS(on)}$		4.0	5.2	mΩ	V_{GS} = 15 V, I_D = 300 A	Fig. 2 Fig. 3
			6.4			V_{GS} = 15 V, I_D = 300 A, T_{VJ} = 175 °C	
Transconductance	g_{fs}		212		S	V_{DS} = 20 V, I_{DS} = 300 A	Fig. 4
			200			V_{DS} = 20 V, I_{DS} = 300 A, T_{VJ} = 175 °C	
Turn-On Switching Energy, T_J = 25 °C T_J = 125 °C T_J = 175 °C	E_{ON}		4.75 5.33 5.88		mJ	V_{DS} = 600 V, I_D = 300 A, V_{GS} = -4 V/15 V, $R_{G(ext)}$ = 2.0 Ω, L = 20.7 µH	Fig. 11 Fig. 13
Turn-Off Switching Energy, T_J = 25 °C T_J = 125 °C T_J = 175 °C	E_{OFF}		4.99 5.23 5.30				
Internal Gate Resistance	$R_{G(int)}$		1.4		Ω	T_{VJ} = 25 °C	
Input Capacitance	C_{iss}		24.5		nF	V_{GS} = 0 V, V_{DS} = 1000 V, V_{AC} = 25 mV, f = 100 kHz	Fig. 9
Output Capacitance	C_{oss}		0.97				
Reverse Transfer Capacitance	C_{rss}		50		pF		
Gate to Source Charge	Q_{GS}		256		nC	V_{DS} = 800 V, V_{GS} = -4 V/15 V I_D = 400 A Per IEC60747-8-4 pg 21	
Gate to Drain Charge	Q_{GD}		308				
Total Gate Charge	Q_G		908				
FET Thermal Resistance, Junction to Case	$R_{th\ JC}$		0.16	0.18	°C/W		Fig. 17

Body Diode Characteristics (Per Position) (T_{VJ} = 25 °C Unless Otherwise Specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions	Note
Body Diode Forward Voltage	V_{SD}		6.0		V	V_{GS} = -4 V, I_{SD} = 300 A	Fig. 7
			5.5			V_{GS} = -4 V, I_{SD} = 300 A, T_J = 175 °C	
Reverse Recovery Time	t_{RR}		36.5		ns	V_{GS} = -4 V, I_{SD} = 300 A , V_R = 600 V di_F/dt = 14.5 A/ns, T_J = 175 °C	
Reverse Recovery Charge	Q_{RR}		7.3		µC		
Peak Reverse Recovery Current	I_{RRM}		323		A		
Reverse Recovery Energy T_J = 25 °C T_J = 125 °C T_J = 175 °C	E_{RR}		0.65 1.98 3.01		mJ	V_{DS} = 600 V, I_D = 300 A, V_{GS} = -4 V/15 V, $R_{G(ext)}$ = 2.0 Ω, L = 20.7 µH	Fig. 14

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Module Physical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Package Resistance, M1	$R_{3\text{-}1}$		0.60		mΩ	T_C = 125 °C, Note 5
Package Resistance, M2	$R_{1\text{-}2}$		0.51			T_C = 125 °C, Note 5
Stray Inductance	L_{Stray}		10.2		nH	Between Terminals 2 and 3
Case Temperature	T_C	-40		125	°C	
Weight	W		300		g	
Mounting Torque	M_S	4.5	5	5.5	N-m	Baseplate, M6 Bolts
		4.5	5	5.5		Power Terminals, M6 Bolts
Case Isolation Voltage	V_{isol}			5.5	kV	AC, 50 Hz, 1 min
Comparative Tracking Index	CTI		600			

Note (5): Total Effective Resistance (Per Switch Position) = MOSFET $R_{DS(on)}$ + Switch Position Package Resistance

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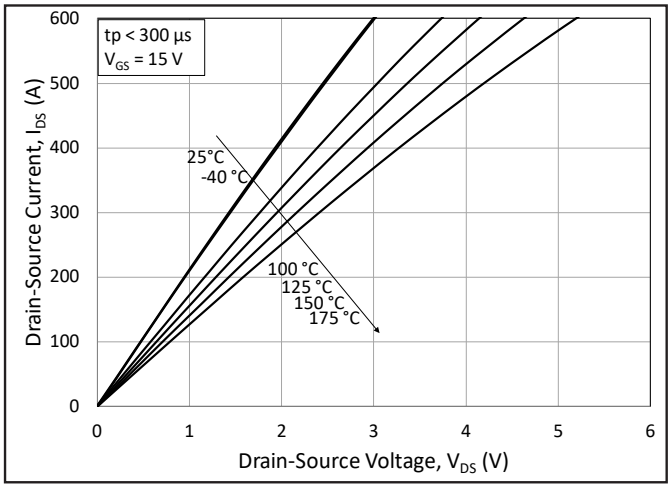


Figure 1. Output Characteristics for Various Junction Temperatures

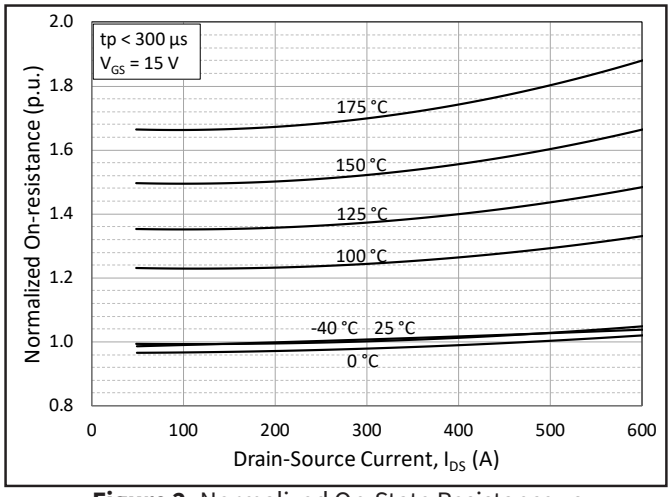


Figure 2. Normalized On-State Resistance vs. Drain Current for Various Junction Temperatures

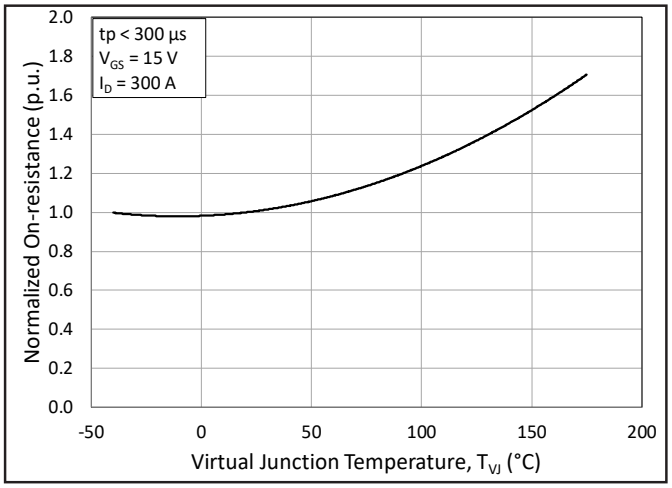


Figure 3. Normalized On-State Resistance vs. Junction Temperature

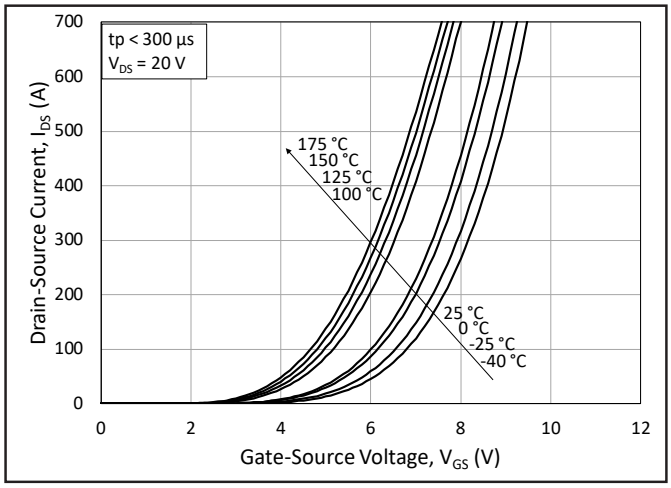


Figure 4. Transfer Characteristic for Various Junction Temperatures

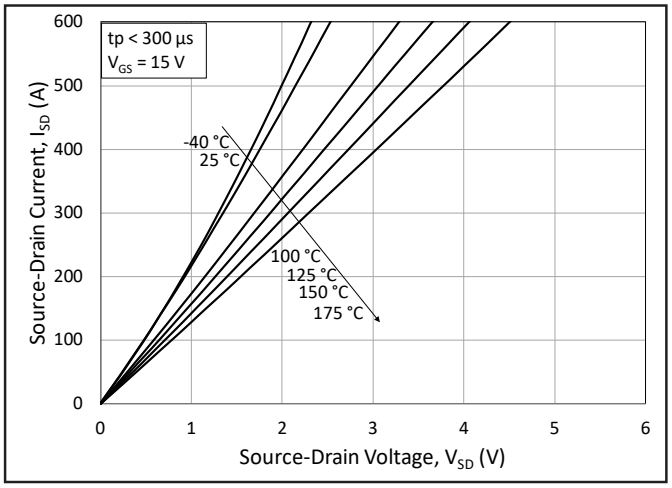


Figure 5. 3rd Quadrant Characteristic vs. Junction Temperatures at V_{GS} = 15 V

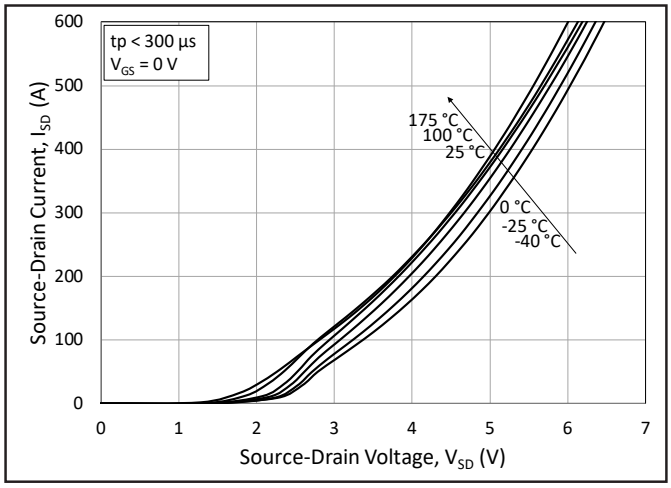


Figure 6. 3rd Quadrant Characteristic vs. Junction Temperatures at V_{GS} = 0 V (Body Diode)

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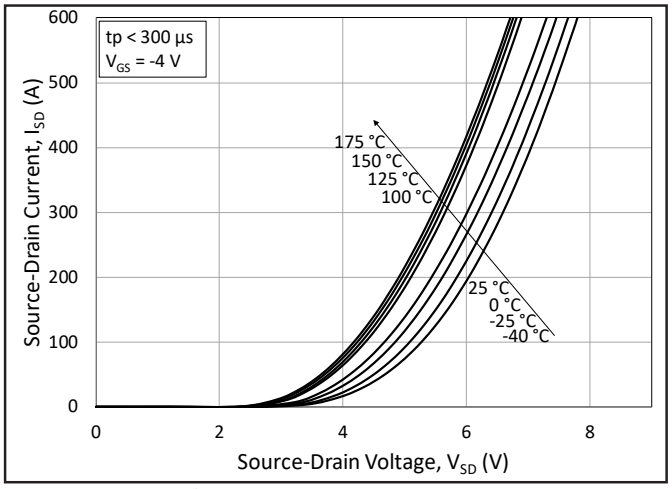


Figure 7. 3rd Quadrant Characteristic vs. Junction Temperatures at V_{GS} = - 4 V (Body Diode)

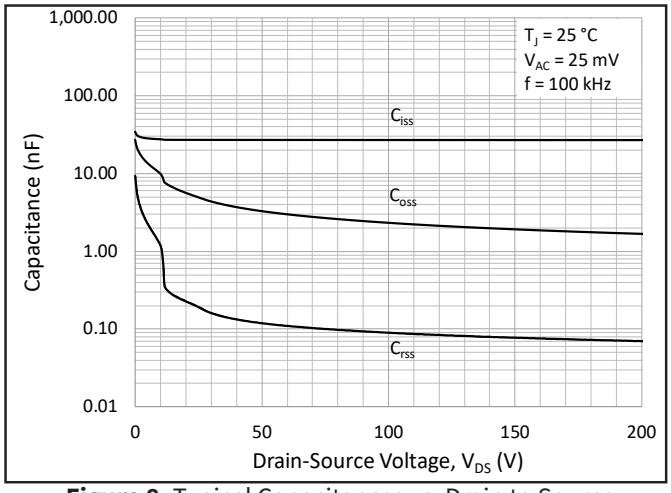


Figure 8. Typical Capacitances vs. Drain to Source Voltage (0 - 200V)

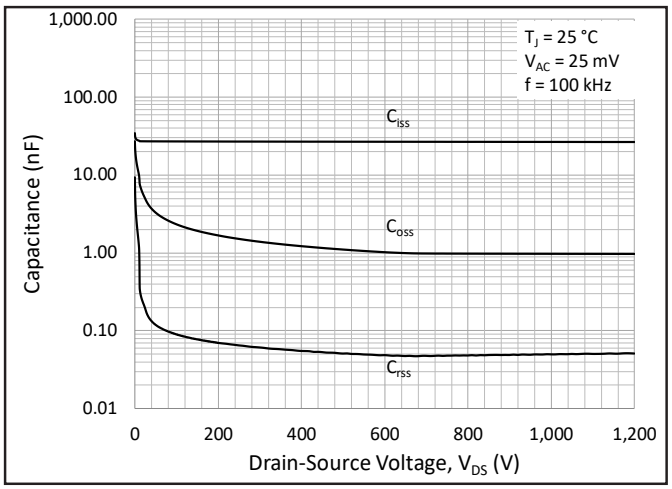


Figure 9. Typical Capacitances vs. Drain to Source Voltage (0 - 1200V)

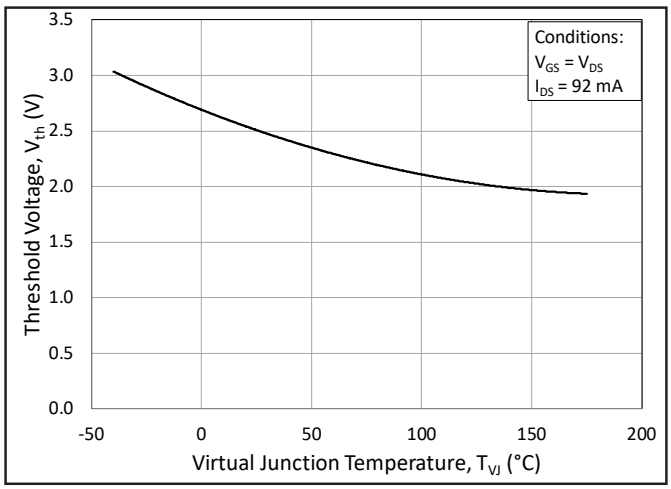


Figure 10. Threshold Voltage vs. Junction Temperature

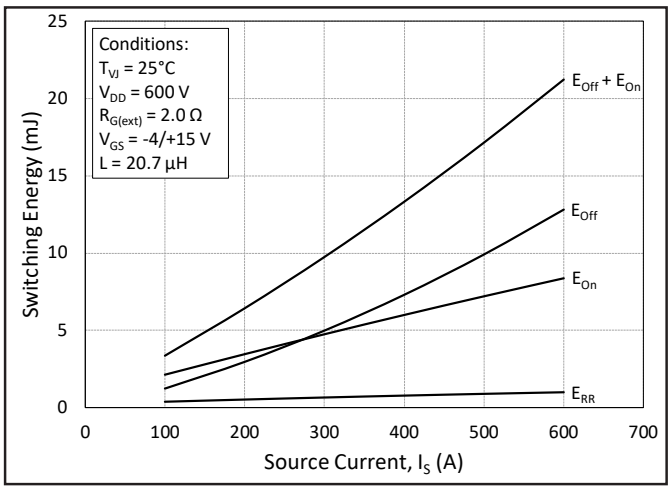


Figure 11. Switching Energy vs. Drain Current (V_{DS} = 600 V)

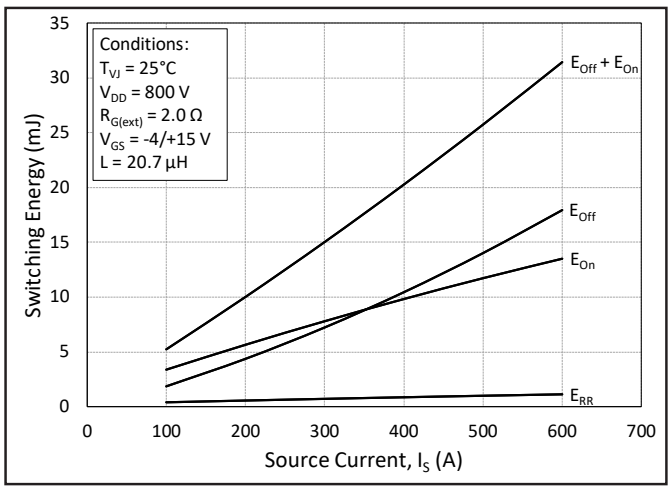


Figure 12. Switching Energy vs. Drain Current (V_{DS} = 800 V)

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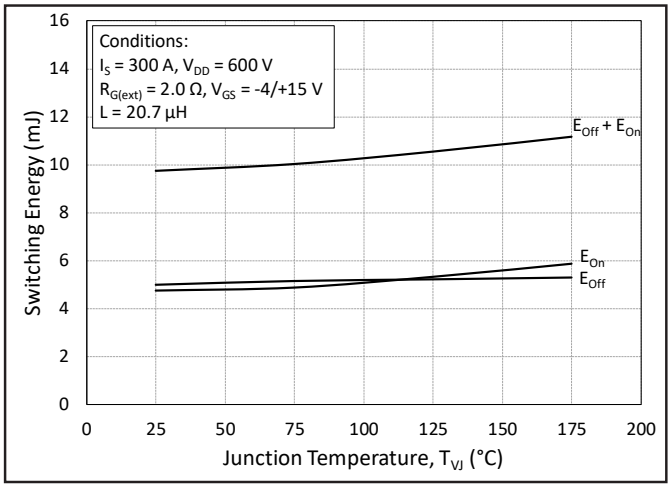


Figure 13. MOSFET Switching Energy vs. Junction Temperature

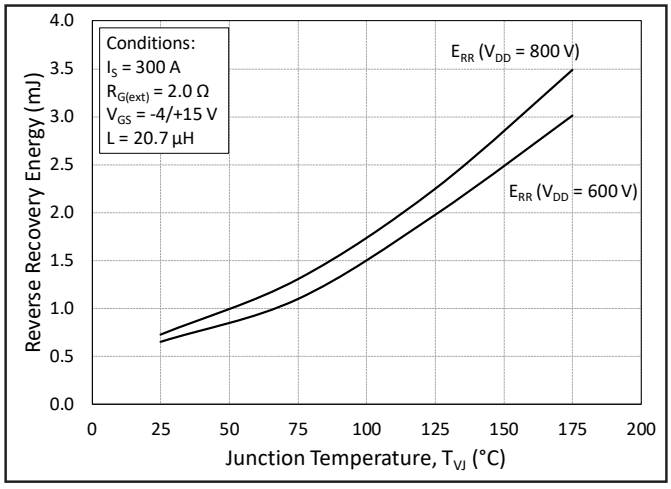


Figure 14. Reverse Recovery Energy vs. Junction Temperature

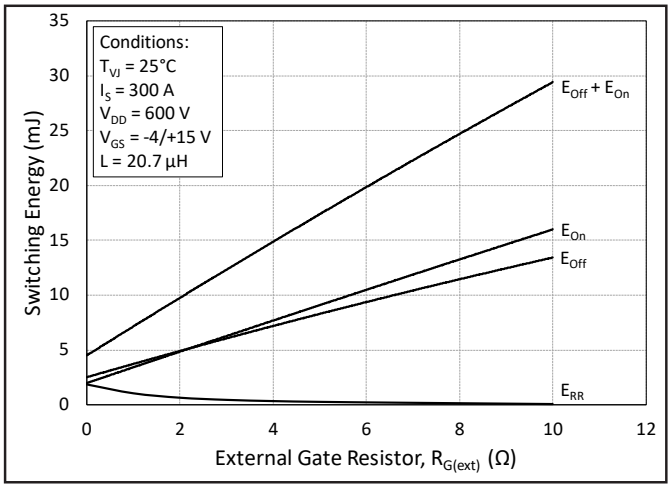


Figure 15. MOSFET Switching Energy vs. External Gate Resistance

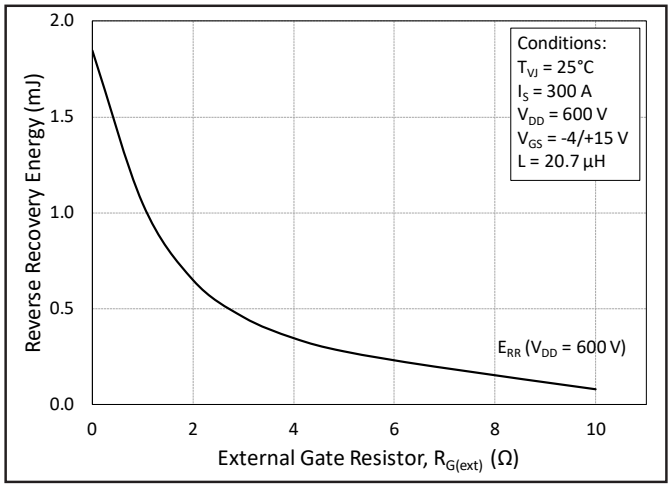


Figure 16. Reserve Recovery Energy vs. External Gate Resistance

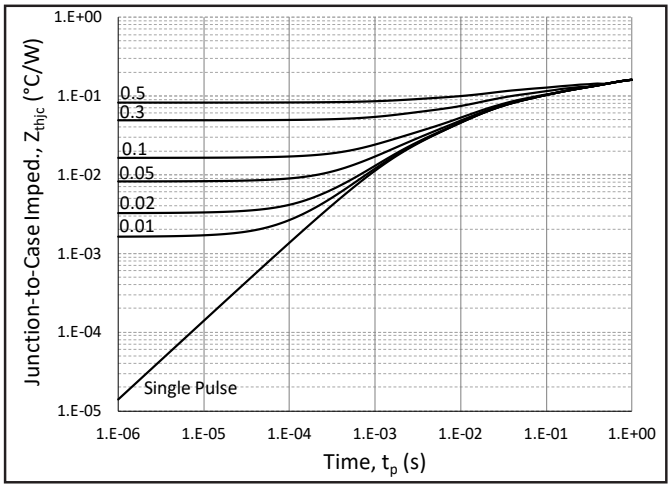


Figure 17. MOSFET Juction to Case Transient Thermal Impedance, $Z_{th\ JC}$ (°C/W)

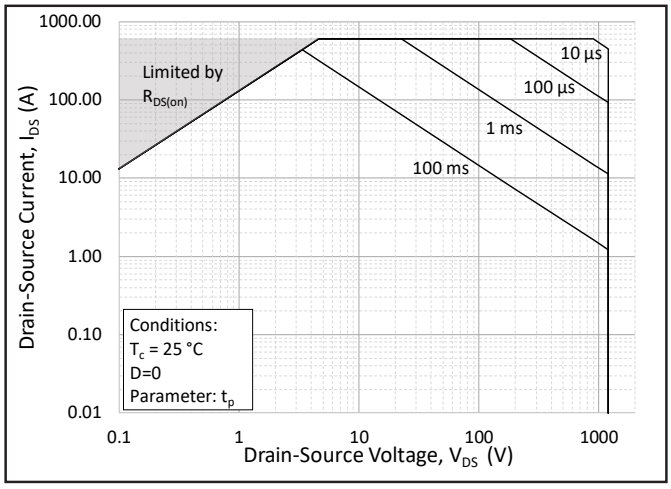


Figure 18. Forward Bias Safe Operating Area (FBSOA)

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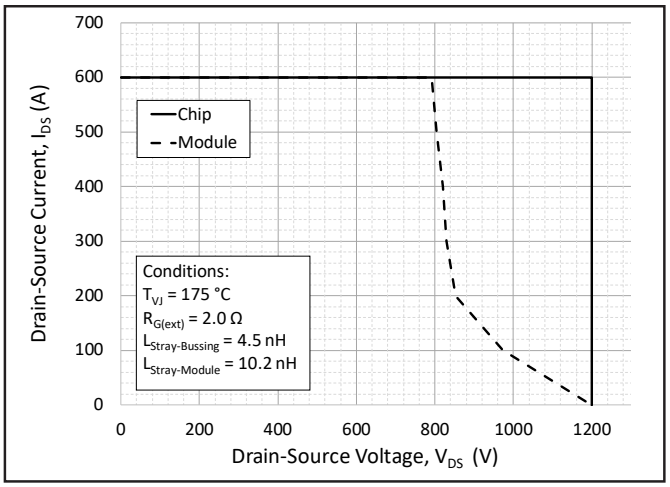


Figure 19. Reverse Bias Safe Operating Area (RBSOA)

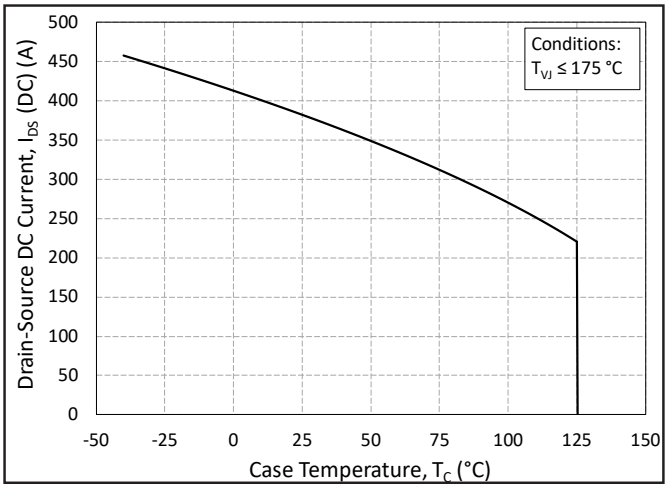


Figure 20. Continuous Drain Current Derating vs. Case Temperature

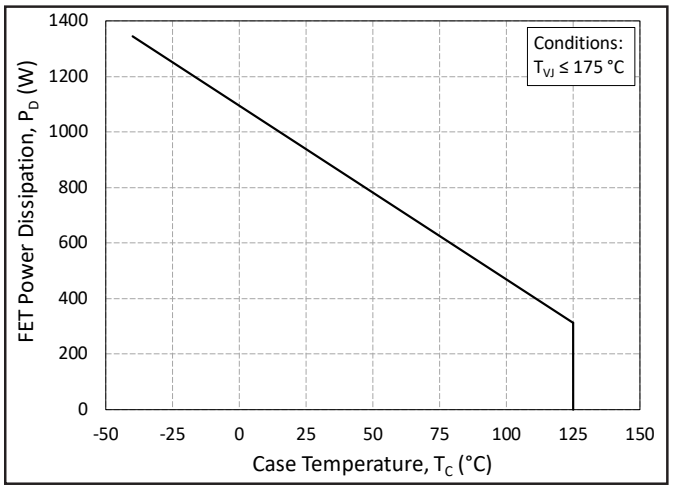


Figure 21. Maximum Power Dissipation Derating vs. Case Temperature

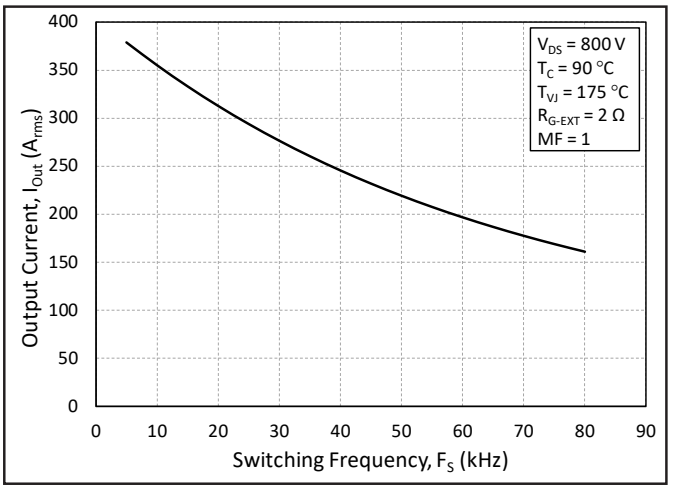


Figure 22. Typical Ouput Current Capablity vs. Switching Frequency (Inverter Application)

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Timing Characteristics

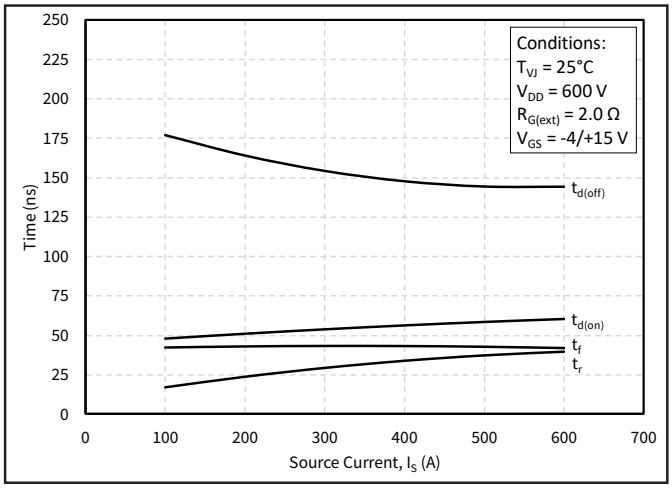


Figure 23. Timing vs. Source Current

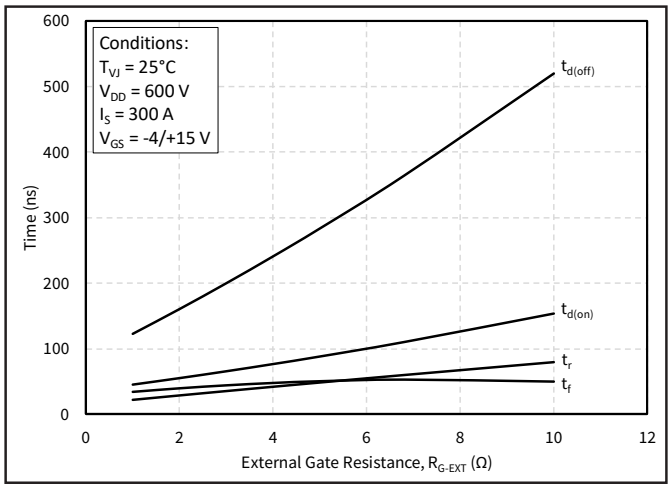


Figure 24. Timing vs. External Gate Resistance

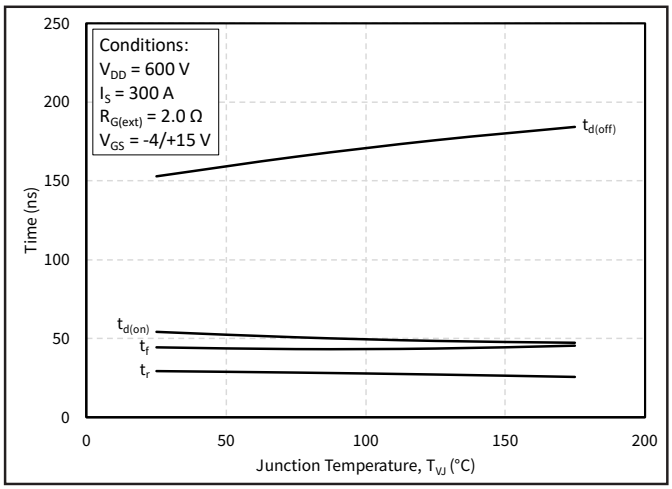


Figure 25. Timing vs. Junction Temperature

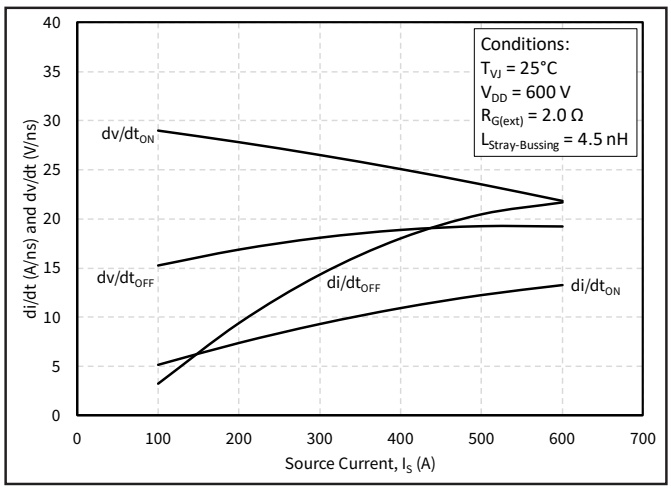


Figure 26. dv/dt and di/dt vs. Source Current

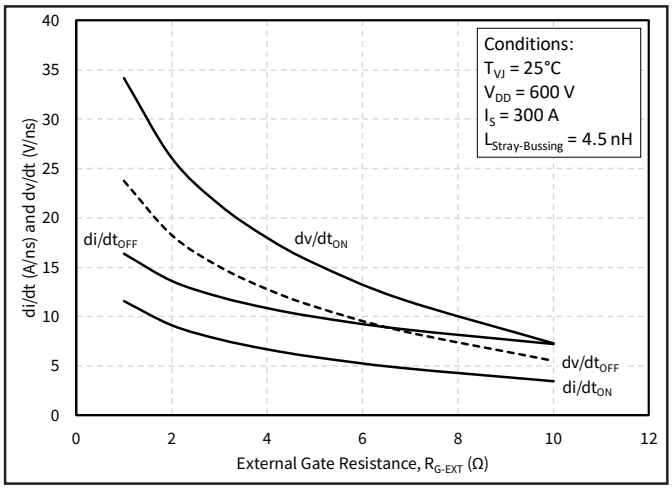


Figure 27. dv/dt and di/dt vs. External Gate Resistance

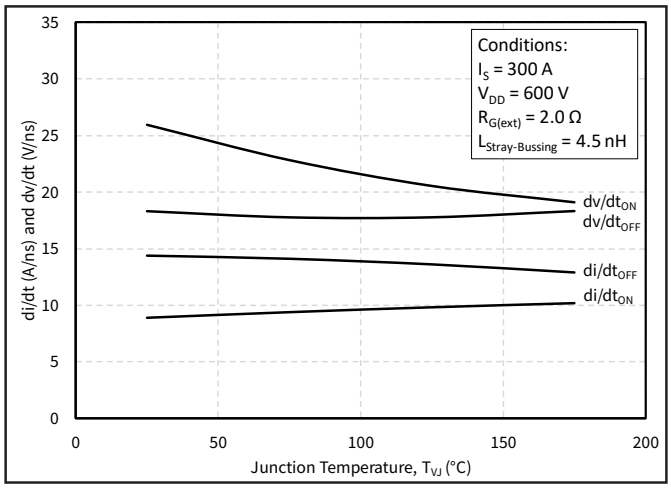


Figure 28. dv/dt and di/dt vs. Junction Temperature

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Definitions

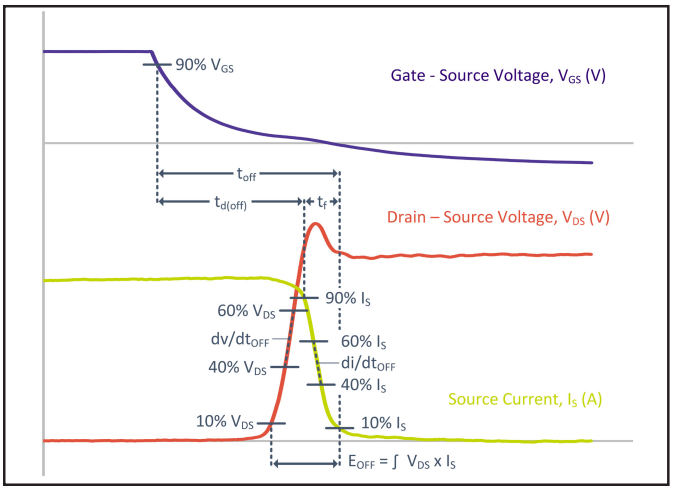


Figure 29. Turn-Off Transient Definitions

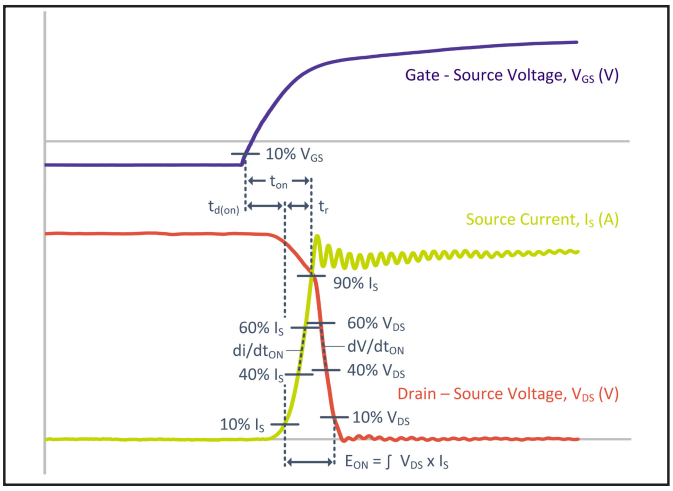


Figure 30. Turn-On Transient Definitions

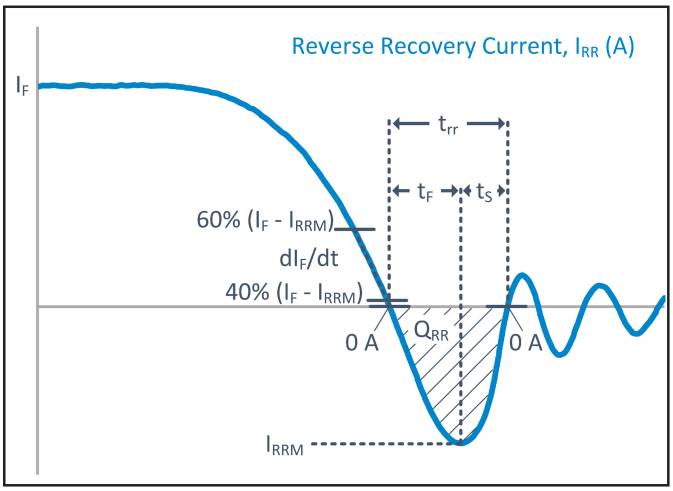


Figure 31. Reverse Recovery Definitions

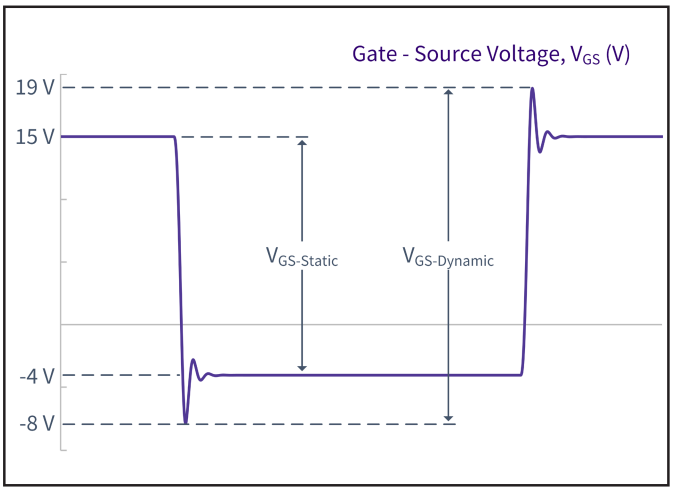
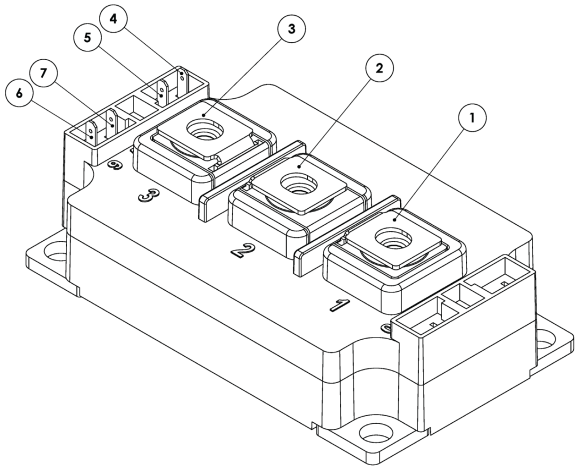
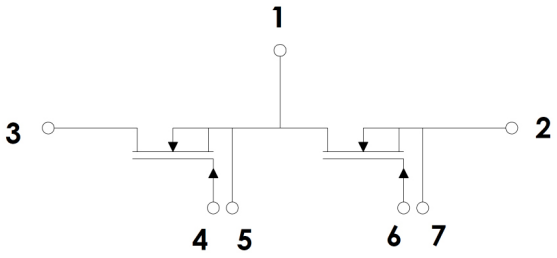


Figure 32. V_{GS} Transient Definitions

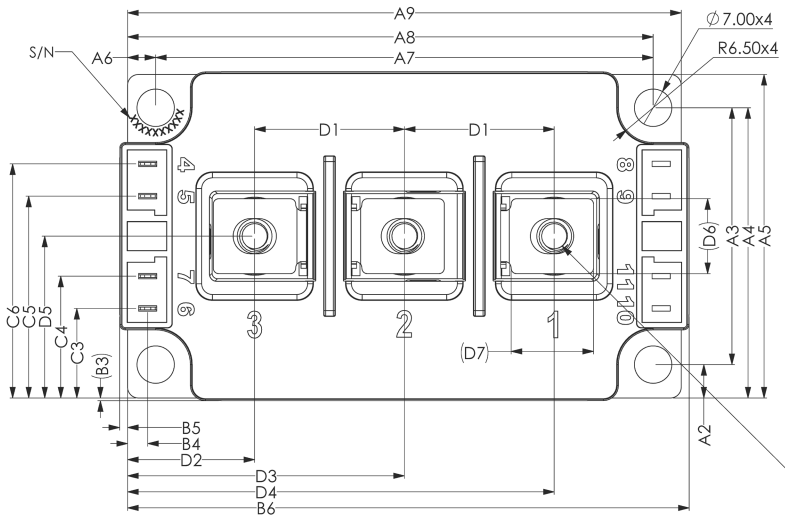
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Schematic and Pin Out

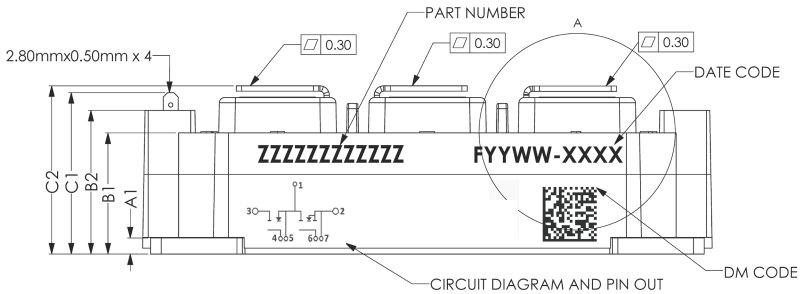


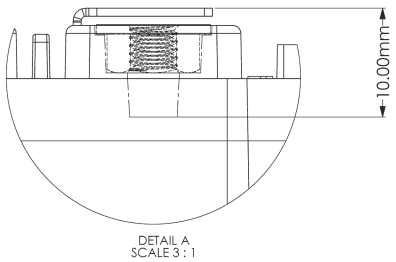


Package Dimensions (mm)



DIMENSION TABLE		
SYMBOL	DIMENSION (mm)	TOLERANCE (mm)
A1	3.00	±0.30
A2	6.22	±0.30
A3	48.00	±0.30
A4	54.22	±0.30
A5	60.44	±0.30
A6	5.25	±0.30
A7	93	±0.30
A8	98.25	±0.30
A9	103.50	±0.30
B1	22.75	±0.30
B2	27.30	±0.30
B3	0.51 x 2	REF
B4	3.76	±0.40
B5	1.25	±0.40
B6	105.00	±0.30
C1	30.60	±0.50
C2	31.40	±0.40
C3	16.72	±0.40
C4	22.75	±0.40
C5	37.7	±0.40
C6	43.73	±0.40
D1	28.00	±0.50
D2	24.20	±0.40
D3	52.00	±0.40
D4	79.80	±0.40
D5	30.22	±0.40
D6	14.00 x 3	REF
D7	15.40 x 3	REF





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Supporting Links & Tools

- CGD1200HB2P-BM3 Evaluation Gate Driver
- CGD12HB00D: Differential Transceiver Board
- KIT-CRD-CIL12N-BM: Dynamic Performance Evaluation Board for the BM2 & BM3 Module (CPWR-AN-36)
- CPWR-AN-34: Module Mounting Application Note
- CPWR-AN-35: Thermal Interface Material Application Note

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